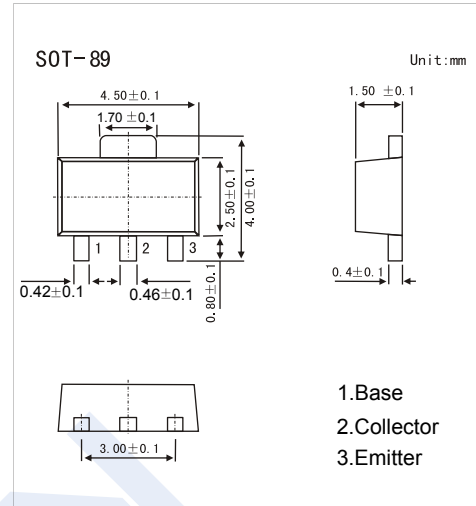


PNP Transistors

2SA1201-HF

■ Features

- High voltage
- High transition frequency
- Complementary to 2SC2881-HF
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CB0}	-120	V
Collector - Emitter Voltage	V_{CE0}	-120	
Emitter - Base Voltage	V_{EB0}	-5	
Collector Current - Continuous	I_C	-0.8	A
Collector Power Dissipation	P_C	0.5	W
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature range	T_{stg}	-55 to 150	

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V_{CB0}	$I_C = -1\text{mA}, I_E = 0$	-120			V
Collector- emitter breakdown voltage	V_{CE0}	$I_C = -10\text{mA}, I_B = 0$	-120			
Emitter - base breakdown voltage	V_{EB0}	$I_E = -1\text{mA}, I_C = 0$	-5			
Collector-base cut-off current	I_{CB0}	$V_{CB} = -120\text{V}, I_E = 0$			-100	nA
Emitter cut-off current	I_{EB0}	$V_{EB} = -5\text{V}, I_C = 0$			-100	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -500\text{mA}, I_B = -50\text{mA}$			-1	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -500\text{mA}, I_B = -50\text{mA}$			-1.2	
Base - emitter voltage	V_{BE}	$V_{CE} = -5\text{V}, I_C = -500\text{mA}$			-1	
DC current gain	h_{FE}	$V_{CE} = -5\text{V}, I_C = -100\text{mA}$	80		240	
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$			30	pF
Transition frequency	f_T	$V_{CE} = -5\text{V}, I_C = -100\text{mA}$		120		MHz

■ Classification of h_{FE}

Type	2SA1201-O-HF	2SA1201-Y-HF
Range	80-160	120-240
Marking	DO _F	DY _F

PNP Transistors

2SA1201-HF

Typical Characteristics

